

# **HD74LS273**

# Octal D-type Positive-edge-triggered Flip-Flops (with Clear)

REJ03D0473-0300 Rev.3.00 Jul.15.2005

The HD74LS273, positive-edge-triggered flip-flops utilize LS TTL circuitry to implement D-type flip-flop logic with a direct clear input.

Information at the D inputs meeting the setup time requirements is transferred to the Q outputs on the positive-going edge of the clock pulse.

When the clock input is at either the high or low level, the D input signal has no effect at the output.

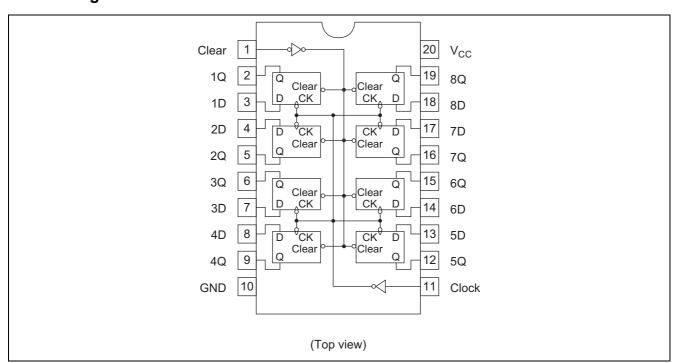
#### **Features**

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS273P	DILP-20 pin	PRDP0020AC-B (DP-20NEV)	Р	_
HD74LS273FPEL	SOP-20 pin (JEITA)	PRSP0020DD-B (FP-20DAV)	FP	EL (2,000 pcs/reel)
HD74LS273RPEL	SOP-20 pin (JEDEC)	PRSP0020DC-A (FP-20DBV)	RP	EL (1,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

#### **Pin Arrangement**



#### **Function Table**

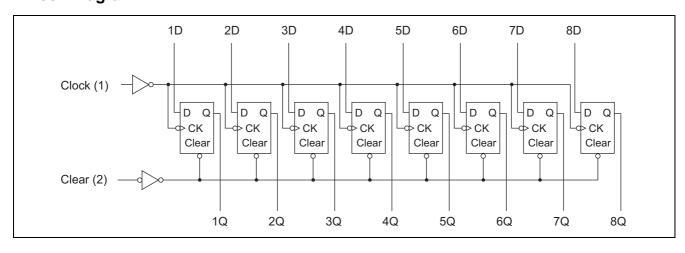
	Output		
Clear	Clock	D	Q
L	X	X	L
Н	1	Н	Н
Н	<b>↑</b>	L	L
Н	L	X	$Q_0$

Notes: H; high level, L; low level, X; irrelevant

1; transition from low to high level

Q<sub>0</sub>; level of Q before the indicated steady-state input conditions were established.

# **Block Diagram**



### **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit
Supply voltage	V <sub>CC</sub>	7	V
Input voltage	$V_{IN}$	7	V
Power dissipation	P <sub>T</sub>	400	mW
Storage temperature	Tstg	-65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

### **Recommended Operating Conditions**

Item	Symbol	Min	Тур	Max	Unit
Supply voltage	V <sub>cc</sub>	4.75	5.00	5.25	V
Output ourrant	I <sub>OH</sub>	_	_	-400	μΑ
Output current	I <sub>OL</sub>	_	—       -400       μA         —       8       mA         25       75       °C         —       30       MHz         —       ns         —       ns         ns       ns		
Operating temperature	Topr	-20	25	75	°C
Clock frequency	fclock	0	_	30	MHz
Clock pulse width	t <sub>w (clock)</sub>	20	_	_	ns
Clear pulse width	t <sub>w (clear)</sub>	20	_	_	ns
Data setup time	t <sub>su (data)</sub>	20↑	_	_	ns
Clear (inactive-state) setup time	t <sub>su (clear)</sub>	25↑	_	_	ns
Data hold time	t <sub>h (data)</sub>	5↑	_	_	ns

#### **Electrical Characteristics**

 $(Ta = -20 \text{ to } +75 \text{ }^{\circ}\text{C})$ 

Item	Symbol	min.	typ.*	max.	Unit	Condition	
Input voltage	$V_{IH}$	2.0	_	_	V		
Input voltage	$V_{IL}$	_	_	0.8	V		
Output valtage	V <sub>OH</sub>	2.7			<b>V</b>	$V_{CC} = 4.75 \; V, \; V_{IH} = 2 \; V, \; V_{IL} = 0.8 \; V, \\ I_{OH} = -400 \; \mu A$	
Output voltage	V <sub>OL</sub>			0.5	V	$I_{OL} = 8 \text{ mA}$ $V_{CC} = 4.75 \text{ V}, V_{IH} = 2 \text{ V},$	
				0.4		$I_{OL} = 4 \text{ mA}$ $V_{IL} = 0.8 \text{ V}$	
	I <sub>IH</sub>			20	μΑ	$V_{CC} = 5.25 \text{ V}, V_I = 2.7 \text{ V}$	
Input current	ᆜ			-0.4	mA	$V_{CC} = 5.25 \text{ V}, V_I = 0.4 \text{ V}$	
	1			0.1	mA	V <sub>CC</sub> = 5.25 V, V <sub>I</sub> = 7 V	
Short-circuit output current	los	-20	_	-100	mA	V <sub>CC</sub> = 5.25 V	
Supply current	I <sub>CC</sub> **	_	17	27	mA	V <sub>CC</sub> = 5.25 V	
Input clamp voltage	V <sub>IK</sub>	_	_	-1.5	V	$V_{CC} = 4.75 \text{ V}, I_{IN} = -18 \text{ mA}$	

Notes:  $^*V_{CC} = 5 \text{ V}$ ,  $Ta = 25^{\circ}C$ 

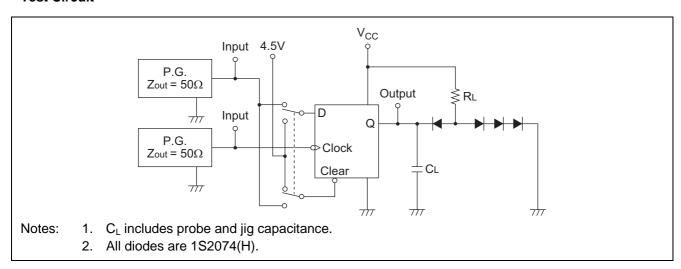
# **Switching Characteristics**

 $(V_{CC} = 5 \text{ V}, \text{Ta} = 25^{\circ}\text{C})$ 

Item	Symbol	Inputs	min.	typ.	max.	Unit	Condition
Maximum clock frequency	$f_{\sf max}$	Clock	30	40	_	MHz	
Propagation delay time	t <sub>PHL</sub>	Clear	_	18	27		$C_L$ = 15 pF, $R_L$ = 2 k $\Omega$
	t <sub>PLH</sub>	Clock	_	17	27	ns	
	t <sub>PHL</sub>		_	18	27		

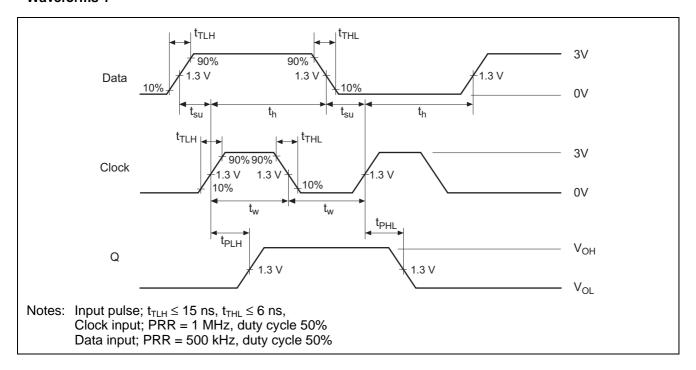
# **Testing Method**

#### **Test Circuit**

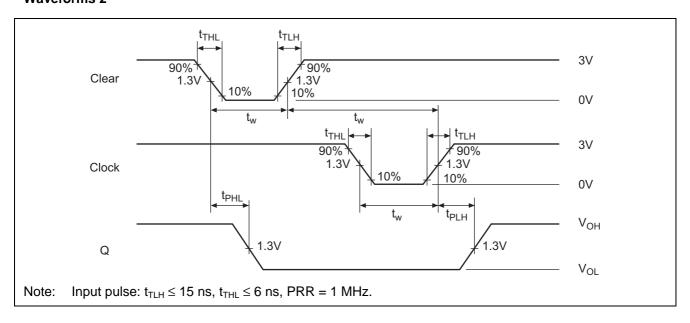


<sup>\*\*</sup> With all outputs open and 4.5 V applied to all data and clear inputs, I<sub>CC</sub> is measured after a momentary ground, then 4.5 V is applied to clock.

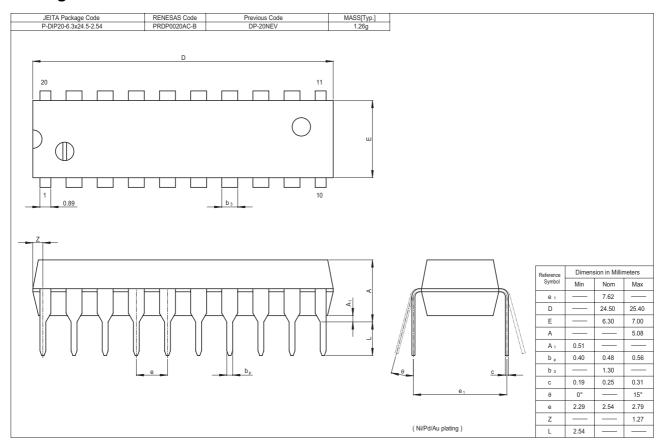
#### Waveforms 1

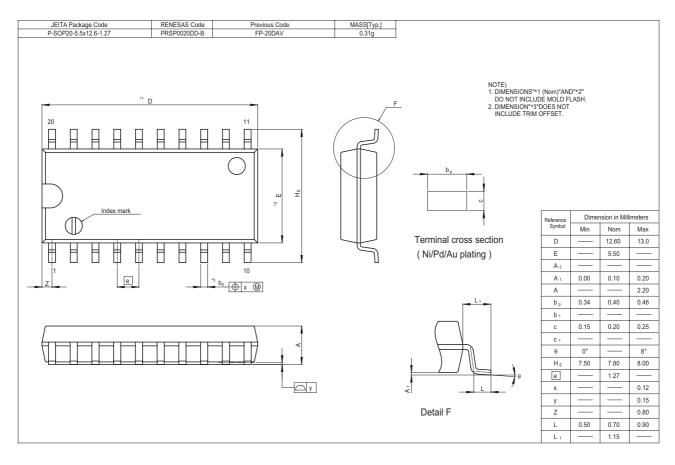


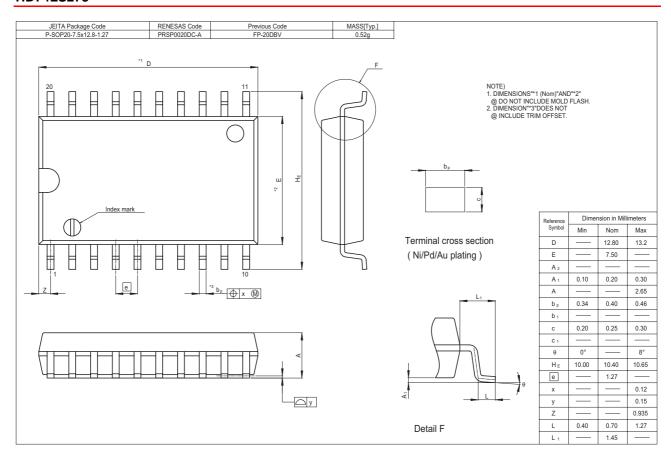
#### Waveforms 2



### **Package Dimensions**







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